

#### Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of <a href="http://www.nxp.com">http://www.nxp.com</a>, <a href="http://www.semiconductors.philips.com/">http://www.nxp.com</a>, <a href="http://www.nexperia.com/">http://www.nexperia.com/</a>, <a href="http://www.nexperia.com/">http://www.nexperia.com/</a>, <a href="http://www.nexperia.com/">use http://www.nexperia.com/</a>

Instead of sales.addresses@www.nxp.com or sales.addresses@www.semiconductors.philips.com, use salesaddresses@nexperia.com (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

Should be replaced with:

- © Nexperia B.V. (year). All rights reserved.

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia



## PUMX2

# NPN/NPN general-purpose double transistors Rev. 02 — 17 November 2009

Product data sheet

#### **Product profile** 1.

## 1.1 General description

NPN/NPN general-purpose double transistors in a small SOT363 (SC-88) Surface Mounted Device (SMD) plastic package.

#### 1.2 Features

- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

## 1.3 Applications

General-purpose switching and amplification

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
I <sub>C</sub>	collector current		-	-	150	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = 6 \text{ V}; I_{C} = 1 \text{ mA}$	120	250	560	

#### **Pinning information** 2.

Table 2. **Pinning** 

Pin	Description	Simplified outline	Symbol
1	emitter TR1		
2	emitter TR2		6 5 4
3	base TR2		TR1 TR2
4	collector TR2	0	
5	base TR1	□1 □2 □3	1 2 3
6	collector TR1		006aaa653



NXP Semiconductors PUMX2

## NPN/NPN general-purpose double transistors

## 3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
PUMX2	SC-88	plastic surface mounted package; 6 leads	SOT363	

## 4. Marking

Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
PUMX2	Z1*

<sup>[1] \* = -:</sup> made in Hong Kong

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit		
Per transist	Per transistor						
$V_{CBO}$	collector-base voltage	open emitter	-	60	V		
$V_{CEO}$	collector-emitter voltage	open base	-	50	V		
$V_{EBO}$	emitter-base voltage	open collector	-	7	V		
I <sub>C</sub>	collector current		-	150	mA		
I <sub>CM</sub>	peak collector current	$single pulse; \\ t_p \leq 1 \ ms$	-	200	mA		
I <sub>BM</sub>	peak base current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-	100	mA		
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> -	180	mW		
Per device							
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> -	300	mW		
T <sub>stg</sub>	storage temperature		-65	+150	°C		
Tj	junction temperature		-	150	°C		
T <sub>amb</sub>	ambient temperature		-65	+150	°C		

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

## 6. Thermal characteristics

Table 6. Thermal characteristics

10010 01	Thornal orial actoriones					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	stor					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	694	K/W
Per device	)					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	417	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

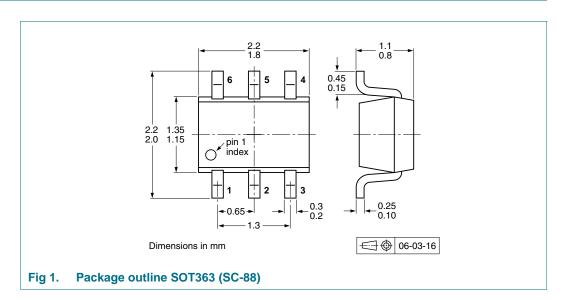
## 7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
I <sub>CBO</sub>	collector-base	$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
	cut-off current	$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 7 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 6 \text{ V}; I_{C} = 1 \text{ mA}$	120	250	560	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}$	-	-	250	mV
f <sub>T</sub>	transition frequency	$V_{CE} = 12 \text{ V}; I_E = 2 \text{ mA};$ f = 100 MHz	100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 12 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF

## 8. Package outline



## 9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing qua	intity
				3000	10000
PUMX2	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

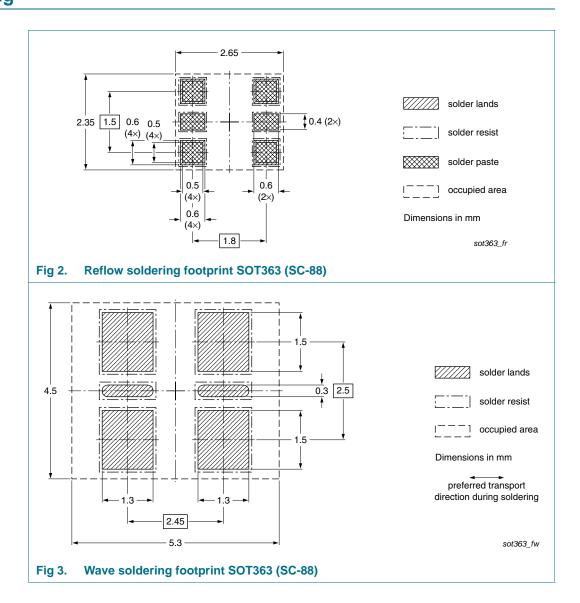
<sup>[1]</sup> For further information and the availability of packing methods, see  $\underline{\text{Section } 13}$ .

[2] T1: normal taping

[3] T2: reverse taping



## 10. Soldering



## 11. Revision history

#### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PUMX2_2	20091117	Product data sheet	-	PUMX2_1
Modifications:	including new content.	eet was changed to reflect the v legal definitions and disclaim	ers. No changes were	
	<ul><li>Figure 1 "Pac</li></ul>	ckage outline SOT363 (SC-88	<u>)"</u> : updated	
	<ul><li>Figure 2 "Ref</li></ul>	low soldering footprint SOT36	3 (SC-88)": updated	
	<ul><li>Figure 3 "Wa</li></ul>	ve soldering footprint SOT363	(SC-88)": updated	
PUMX2_1	20051110	Product data sheet	-	-

NXP Semiconductors PUMX2

#### NPN/NPN general-purpose double transistors

## 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

#### 12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

#### 12.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental

damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

#### 12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

#### 13. Contact information

For more information, please visit: <a href="http://www.nxp.com">http://www.nxp.com</a>

For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

PUMX2\_2 © NXP B.V. 2009. All rights reserved.

PUMX2 **NXP Semiconductors** 

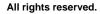
## NPN/NPN general-purpose double transistors

## 14. Contents

1	Product profile
1.1	General description 1
1.2	Features
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 1
3	Ordering information
4	Marking 2
5	Limiting values
6	Thermal characteristics 3
7	Characteristics 3
8	Package outline 4
9	Packing information 4
10	Soldering 5
11	Revision history 6
12	Legal information 7
12.1	Data sheet status 7
12.2	Definitions
12.3	Disclaimers
12.4	Trademarks 7
13	Contact information 7
14	Contents 8

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.







founded by

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Nexperia manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE158 NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460
2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SD2150T100R SP000011176 FMMTA92QTA 2N2369ADCSM
2N5769 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E
US6T6TR NJL0281DG 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR MCH6102-TL-E
NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E NTE103 30A02MH-TL-E NSV40301MZ4T1G NTE101 NTE13
NTE15 NTE16001